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Effect of Indium on the Superconducting Transition Temperature of Tin Telluride RUIDAN ZHONG, JOHN SCHNEELOCH, XIAOYA SHI, QIANG LI, JOHN TRANQUADA, GENDA GU, Brookhaven National Laboratory — Indium-doped tin telluride is one of the most appealing topological superconductors. We have grown a series of $\text{Sn}_{1-x}\text{In}_x\text{Te}$ crystals with different indium concentrations ($0.1 \leq x \leq 1.0$). The results show indium doping improves the superconducting transition temperature significantly and is highly related to the indium concentration. The maximum T_c of indium-doped tin telluride polycrystalline is 4.5K for $x=0.4$. Single crystals of $\text{Sn}_{1-x}\text{In}_x\text{Te}$ were also grown by the floating zone method, and their magnetic properties were characterized.

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